TOSHIBA PHOTOCOUPLER InGaAs IRED & PHOTO-TRANSISTOR

TLP293-4

Programmable Controllers Switching Power Supplies Simplex/Multiplex Data Transmissions

TLP293-4 consists of phototransistors optically coupled to InGaAs infrared emitting diodes.

TLP293-4 photocoupler is housed in the very small and thin SO16 package. Since the TLP293-4 is guaranteed wide operating temperature range (Ta=-55 to 125 °C), and high isolation voltage (3750 Vrms), it is suitable for highdensity surface mount applications such as programmable controllers.

- Collector-Emitter Voltage : 80 V (min)
 - Current Transfer Ratio : 50% (min)
 - GB rank: 100% (min)
- **Isolation Voltage** : 3750 Vrms (min)
- Operation temperature range: -55 to 125 °C
- Safety standards

UL-approved: UL1577, File No. E67349

cUL-approved: CSA Component Acceptance Service No.5A,

File No. E67349

CQC- approved : GB4943.1, GB8898



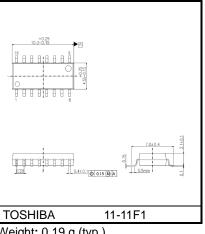
仅适用干海拔 2000 m 以下地区安全使用

VDE-approved : EN60747-5-5 (Note)

Note : When an EN60747-5-5 approved type is needed, please designate the Option (V4).

Construction Mechanical Rating

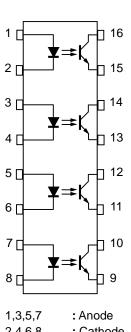
Creepage Distance	5.0 mm (min)
Clearance	5.0 mm (min)
Internal isolation thickness	0.4 mm (min)



Weight: 0.19 g (typ.)

Pin Configuration

TLP293-4



2,4,6,8 : Cathode 9,11,13,15 : Emitter 10,12,14,16 : Collector

Start of commercial production 2014-04

Unit: mm

Current Transfer Ratio (Unless otherwise specified, Ta=25°C)

Rank		Current Tra (%			
(Note 1)	Test condition	IC.	/ IF	Marking of Classification	
		Min	Max		
Blank		50	600	Blank	
GB	IF = 5 mA, VCE = 5 V	100	600	GB	
LA (Note2)	IF = 0.5 mA, VCE = 5 V	50	600	LA	
LGB (Note2)	F = 0.5 mA, VCE = 5 V	100	600	LB	

Note1: Specify both the part number and a rank in this format when ordering.

Example: rank GB: TLP293-4(GB,E

For safety standard certification, however, specify the part number alone. TLP293–4 (GB,E: TLP293-4

Note2: The LA and LGB rank are made CTR rank of the low input current condition.

Absolute Maximum Ratings (Note)(Unless otherwise specified, Ta = 25°C)

	Characteristic	Symbol	Note	Rating	Unit
	Input forward current	lF		50	mA
	Input forward current derating (Ta≥50°C)	ΔIF /ΔTa		-0.59	mA /°C
	Input forward current(Pulsed)	IFP	(Note 1)	1	А
ĒD	Power dissipation	PD		70	mW
	Power dissipation derating(Ta≥50°C)	ΔP _D /ΔTa		-0.82	mW /°C
	Input reverse voltage	VR		5	V
	Junction temperature	Тј		125	°C
	Collector-emitter voltage	VCEO		80	V
	Emitter-collector voltage	VECO		7	V
OR	Collector current	Ic		50	mA
ETECTOR	Collector power dissipation			100	mW
	Collector power dissipation derating(Ta≥25°C) (1 Circuit)	ΔP _C /ΔTa		-0.91	mW /°C
	Junction temperature	Тј		125	°C
	Operating temperature range	Topr		-55 to 125	°C
-	Storage temperature range	T _{stg}		-55 to 125	°C
MOM	Lead soldering temperature Total power dissipation (1 Circuit)			260 (10s)	°C
MOC				170	mW
	Input power dissipation derating(Ta≥25°C) (1 Circuit)			-1.55	mW /°C
	Isolation Voltage AC, 60s, R.H.≤60%	BVS	(Note 2)	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Pulse width \leq 100 μ s, frequency 100 Hz

Note2: This device is considered as a two-terminal device: All pins on the LED side are shorted together, and all pin on the photodetector side are shorted together.

Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
	Input forward voltage	VF	IF = 10 mA	1.1	1.25	1.4	V
LED	Input reverse current	I _R	V _R = 5 V			10	μΑ
	Input capacitance	CT	V = 0 V, f = 1 MHz	_	30	—	pF
	Collector-emitter breakdown voltage	V(BR) CEO	IC = 0.5 mA	80	_	_	V
OR	Emitter-collector breakdown voltage	V(BR) ECO	IE = 0.1 mA	7	_	_	V
DETECTOR	Dark current		V _{CE} = 48 V,		0.01	0.08	μΑ
DET		Idark	V _{CE} = 48 V, Ta = 85°C		2	50	μΑ
	Collector-emitter capacitance	CCE	V = 0 V, f = 1 MHz	_	10	_	pF

Coupled Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Current transfer ratio	IC / IF	IF = 5 mA, VCE = 5 V	50	_	600	%
	IC / IF	Rank GB	100	—	600	70
Saturated current transfer ratio	IC / IF (sat)	I _F = 1 mA, V _{CE} = 0.4 V	_	60	_	%
Saturated current transfer ratio		Rank GB	30	_	_	70
		IC = 2.4 mA, IF = 8 mA	_	_	0.3	
Collector-emitter saturation voltage	VCE (sat)	IC = 0.2 mA, IF = 1 mA	_	0.2	_	V
		Rank GB	_	_	0.3	
Off-state collector current	I _{C (off)}	V _F = 0.7 V, V _{CE} = 48 V	_	_	10	μA

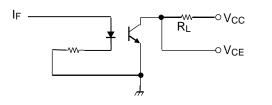
Isolation Characteristics (Unless otherwise specified, Ta = 25°C)

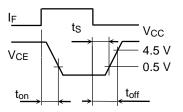
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Total capacitance (input to output)	CS	V _S = 0 V, f = 1 MHz	_	0.8	—	pF
Isolation resistance	Rs	V _S = 500 V, R.H.≤60%	1×10 ¹²	10 ¹⁴	_	Ω
		AC , 60 s	3750		_	Vrms
Isolation voltage	BVS	AC , 1 s in OIL	_	10000	_	VIIIIS
		DC , 60 s in OIL	_	10000		Vdc

Switching Characteristics (Unless otherwise specified, Ta = 25°C)

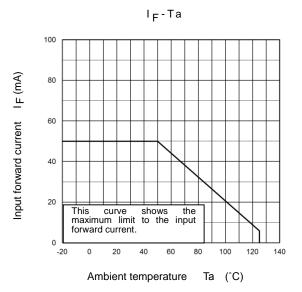
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Rise time	tr		_	2	_	
Fall time	tf	V _{CC} = 10 V, I _C = 2 mA	_	3	—	
Turn-on time	t _{on}	R _L = 100 Ω	_	3	—	μS
Turn-off time	toff		_	3	—	
Turn-on time	ton		_	1.5	—	
Storage time	ts	$R_L = 1.9 k\Omega$ (Figure 1) V _{CC} = 5 V, I _F = 16 mA		20	_	μS
Turn-off time	toff		_	35	_	

Figure 1: Switching Time Test Circuit

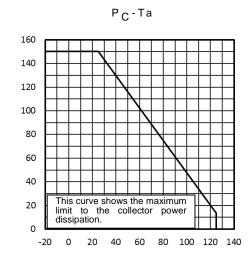




Characteristics Curves (Note)



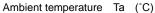
IFP-DR



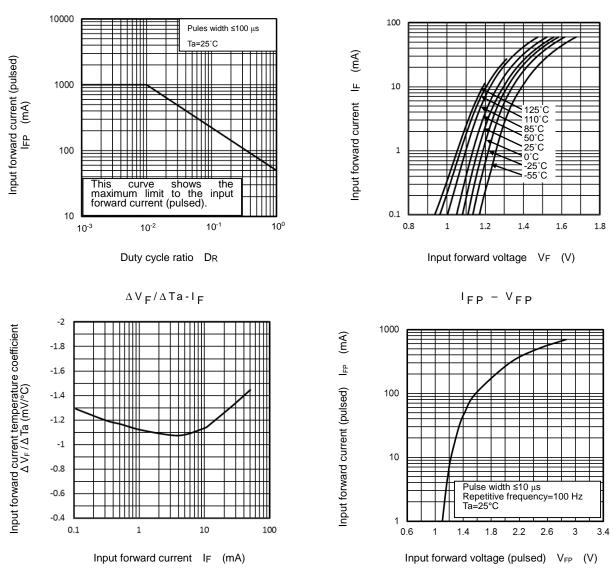
(MM)

۳ C

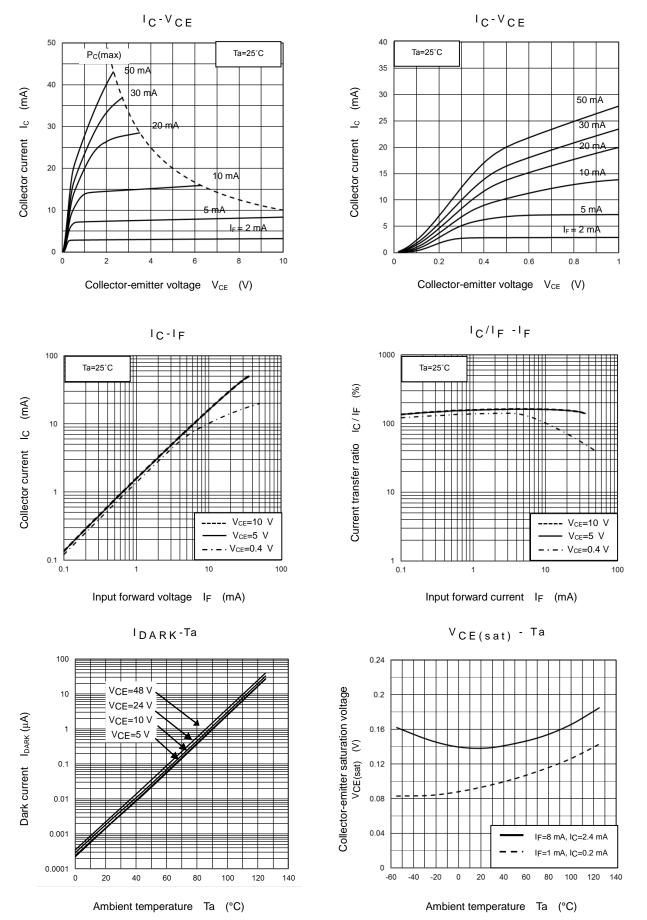
Collector power dissipation



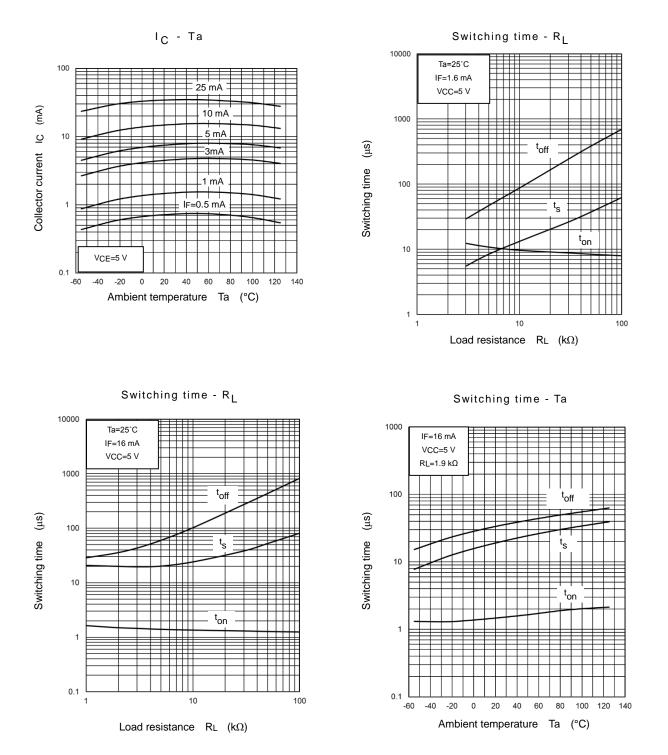




Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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Soldering and Storage

1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespectiveof whether a soldering iron or a reflow soldering method is used.

Min

150

60

60

217

 T_{S}

ts

ΤL

tL

Τ_Ρ

t_P

Max

200

120

3

150

260

30

6

Unit

°C

s

°C/s

°C

s

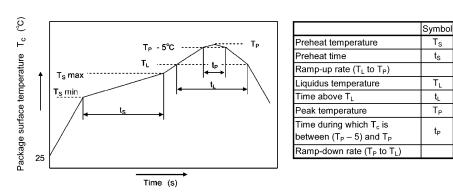
°C

s

°C/s

1) When Using Soldering Reflow

An example of a temperature profile when lead(Pb)-free solder is used



The soldering temperature profile is based on the package surface temperature

- (See the figure shown below, which is based on the package surface temperature.)
- Reflow soldering must be performed once or twice.

 The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

2) When using soldering Flow

 Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds.

- Mounting condition of 260 °C within 10 seconds is recommended
- Flow soldering must be performed once.

3) When using soldering Iron

- Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C
- Heating by soldering iron must be done only once per lead.

2. Precautions for General Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.
- 3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

Option:Specification for Embossed-Tape Packing (TP) for Mini-Flat Coupler

1. Applicable Package

Package Name	Product Type
SO16	Mini-Flat Coupler

2. Product Naming System

Type of package used for shipment is denoted by a symbol suffix after a product number. The method of classification is as below.

Example) TLP293-4(GB-TP,E

Part number: TLP293-4 CTR rank: GB Tape type: TP [[G]]/RoHS COMPATIBLE: E (Note)

Note : Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 Jun 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

3. Tape Dimensions Specification

3.1 Orientation of Device in Relation to Direction of Tape Movement

Device orientation in the recesses is as shown in Figure 3.1.1.

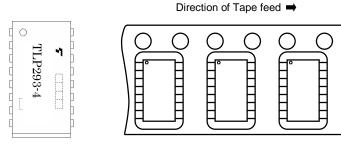


Figure 3.1.1 Device Orientation

3.2 Packing Quantity

2000 pcs per reel

3.3 Empty Device Recesses are as Shown in Table 1.

Table 3.3.1 Empty Device Recesses

	Standard	Remarks
Occurrences of 2 or more successive empty device recesses	0	Within any given 40-mm section of tape, not including leader and trailer
Single empty device recesses	6 device (max) per reel	Not including leader and trailer

3.4 Tape Leader and Trailer

The start end of the tape has 50 or more empty cavities. The hub end of the tape has 50 or more empty cavities and two empty turns only for a cover tape.

3.5 Tape Dimensions

Tape material: Plastic (protection against electrostatics)

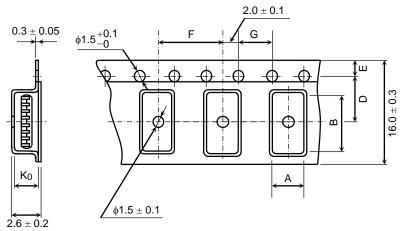


Figure3.5.1 Tape Form

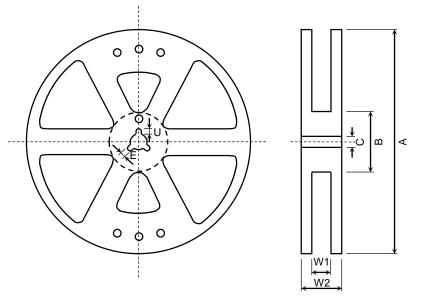
Table 3.5.1	Tape Dimensions
	Tape Dimensions

Unit: mm Unless otherwise specified: ±0.1

		Uniess otherwise specified: ±0.1
Symbol	Dimension	Remark
A	7.5	—
В	10.5	—
D	7.5	Center line of indented square hole and sprocket hole
E	1.75	Distance between tape edge and hole center
F	12.0	Cumulative error +0.1/-0.3(max) per 10 feed holes
G	4.0	Cumulative error +0.1/-0.3(max) per 10 feed holes
K ₀	2.2	Internal space

3.6 Reel specification

Material: Plastic



				-
Table	3.6.1	Reel	Dimen	sions

	Unit: mm
Symbol	Dimension
А	$\phi 330\pm 2$
В	$\varphi 80 \pm 1$
С	$\phi 13 \pm 0.5$
E	2.0 ± 0.5
U	4.0 ± 0.5
W1	17.5 ± 0.5
W2	21.5 ± 1.0

Figure 3.6.1 Reel Dimensions

4. Packing

Either one reel or ten reels(maximum) of photocouplers are packed in a shipping carton.

5. Label Format

The label on each carton and reel provides the part number, quantity, lot number, the Toshiba logo, CTR rank, etc.

6. Ordering Information

When placing an order, please specify the part number, CTR rank, tape type and quantity (must be a multiple of 2000) as shown in the following example.

the following example.

Example) TLP293-4(GB-TP,E 2000 Pcs

Part number: TLP293-4 CTR rank (GB Tape type: TP [[G]]/RoHS COMPATIBLE (Note) Quantity (must be a multiple of 2000)

Note : Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 Jun 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

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